

Notice of References Cited

Application/Control No.

10/509,303

Applicant(s)/Patent Under
Reexamination
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Examiner

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Art Unit

4132

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U.S. PATENT DOCUMENTS

* * *	Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
A	US-4,335,266	06-1982	Mickelsen et al.	136/260
B	US-			
C	US-			
D	US-			
E	US-			
F	US-			
G	US-			
H	US-			
I	US-			
J	US-			
K	US-			
L	US-			
M	US-			

FOREIGN PATENT DOCUMENTS

* * *	Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
N					
O					
P					
Q					
R					
S					
T					

NON-PATENT DOCUMENTS

* * *	Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)				
U	Yamaguchi, Yoshida, Minoura, Structural and compositional analyses on indium sulfide thin films deposited in aqueous chemical bath containing indium chloride and thioacetamide, 2003, Thin Solid Films, 431-432, pp 354-358				
V	Nakada, Furumi, Kunioka, High-Efficiency Cadmium-free Cu(In,Ge)Se ₂ Thin-Film Solar Cells with Chemically Deposited ZnS Buffer Layers, Oct 1999, IEEE Transaction on Electron Devices, Vol 46 No 10, pp 2093-2097				
W	Hashimoto, Kohara, Negami, Nishitani, Wada, Chemical Bath Deposition of CdS buffer layer for CIGS solar cells, 1998, Solar Energy Materials and Solar Cells, 50, pp 71-77				
X	Dona, Herrero, Chemical Bath Deposition of CdS Thin Films: An Approach to the Chemical Mechanism Through Study of the Film Microstructure, 1997, J. Electrochem. Soc., Vol. 144 No. 11, pp 4081-40941				

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.